

Data Sheet

Description

ASDL-4770 is a high performance Infrared emitter that utilizes AlGaAs on GaAs LED technology. It is optimized for high efficiency at emission wavelength of 940nm and is designed for applications that require high radiant intensity, low forward voltage at wide viewing angle. The emitter is encapsulated in Side Look package with spherical side view lens and is matched to ASDL-6770 for maximum sensitivity.

Features

- Side Look Package
- 940nm wavelength
- Low Forward Voltage
- Narrow Viewing Angle
- Good Mechanical and Spectral matching to ASDL-6770 Infrared Phototransistor Detector
- Lead Free and ROHS Compliant
- Available in Tape & Reel

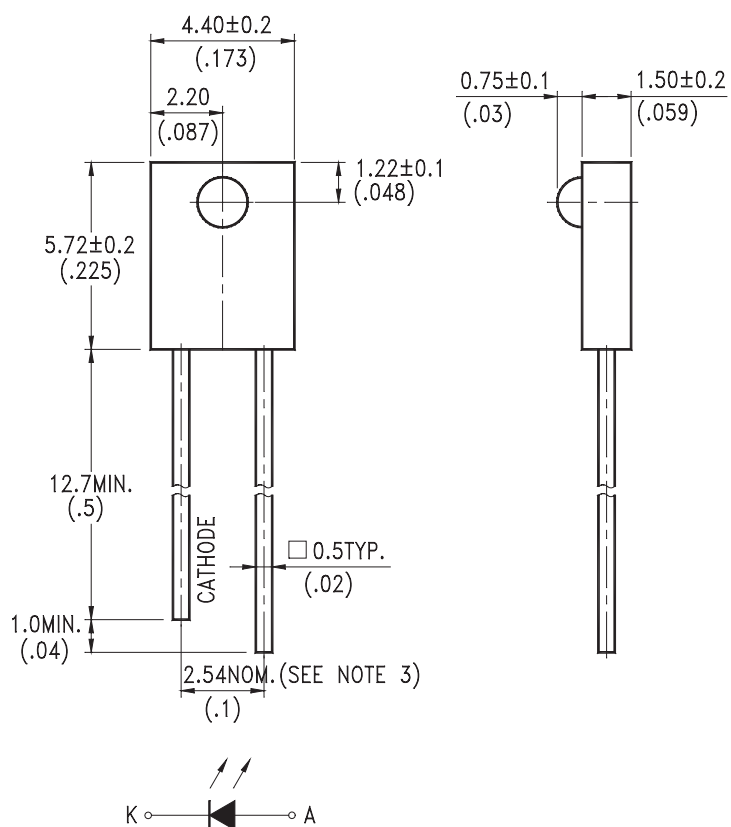
Applications

- Industrial Infrared Monitoring Applications
- Consumer Electronics (Optical Mouse)
- Infrared Source for Optical Counters and Card Readers
- Photo-Interrupters
- On-Off Switch / Beam Interruption
- Light Barriers

Ordering Information

Part Number	Lead Form	Color	Packaging	Shipping Option
ASDL-4770-C22	Straight	Clear	Tape & Reel	4000pcs
ASDL-4770-C41			Bulk	20Kpcs / Carton

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches)
2. Tolerance is $+ 0.25$ mm ($.010$) in unless otherwise noted
3. Protruded resin under flange is 1.0 mm ($.039$) in max
4. Lead spacing is measured where leads emerge from package
5. Specifications are subject to change without notice

Absolute Maximum Ratings at 25°C

Parameter	Symbol	Min.	Max	Unit	Reference
Peak Forward Current	I_{FPK}		1	A	300pps
Continuous Forward Current	I_{FDC}		50	mA	
Power Dissipation	P_{DISS}		75	mW	
Reverse Voltage	V_{R}		5	V	
Operating Temperature	T_{O}	-40	85	°C	
Storage Temperature	T_{S}	-55	100	°C	
LED Junction Temperature	T_{J}		110	°C	
Lead Soldering Temperature			260 °C for 5 sec		

Electrical Characteristics at 25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage	V_{F}		1.2	1.6	V	$I_{\text{FDC}}=20\text{mA}$
Reverse Voltage	V_{R}	5			V	$I_{\text{R}}=100\mu\text{A}$
Thermal Resistance, Junction to Ambient	$R\theta_{\text{JA}}$		350		°C/W	

Optical Characteristics at 25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Radiant On-Axis Intensity	I_{E}	1		2.2	mW/Sr	$I_{\text{FDC}}=20\text{mA}$
Viewing Angle	$2\theta_{1/2}$		40		deg	
Peak wavelength	λ_{PK}		940		nm	$I_{\text{FDC}}=20\text{mA}$
Spectral Width	$\Delta\lambda$		50		nm	$I_{\text{FDC}}=20\text{mA}$
Optical Rise Time	t_{r}		1		us	$I_{\text{FPK}}=100\text{mA}$ Duty Factor=50% Pulse Width=10us
Optical Fall Time	t_{f}		1		us	$I_{\text{FPK}}=100\text{mA}$ Duty Factor=50% Pulse Width=10us

Typical Electrical/Optical Characteristics Curves ($T_A=25^\circ\text{C}$ unless otherwise indicated)

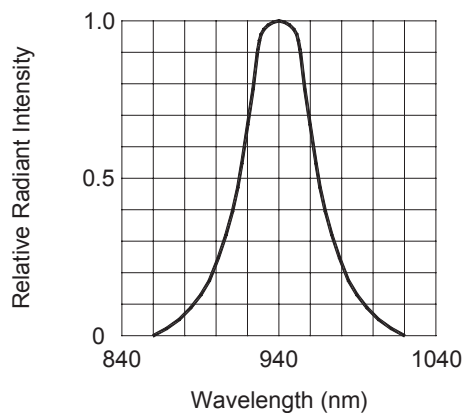


Figure 1. SPECTRAL DISTRIBUTION

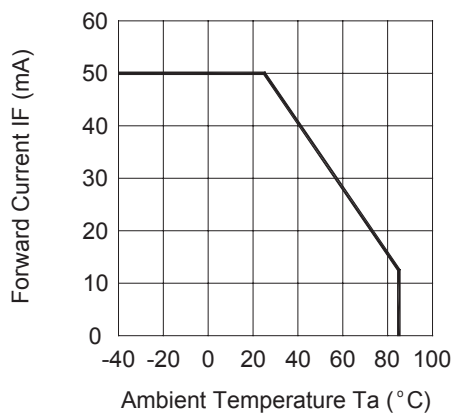


Figure 2. FORWARD CURRENT VS. AMBIENT TEMPERATURE

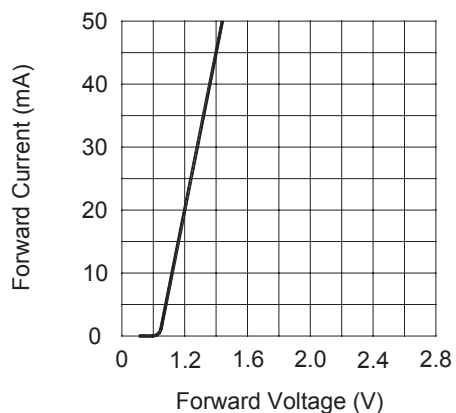


Figure 3. FORWARD CURRENT VS. FORWARD VOLTAGE

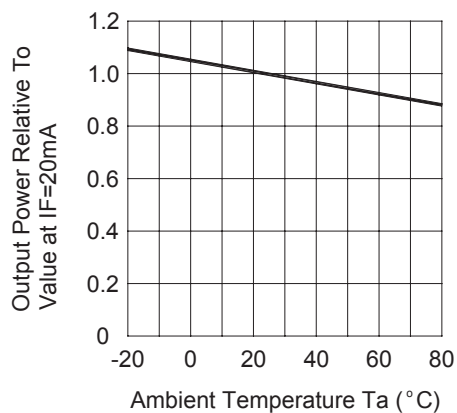


Figure 4. RELATIVE RADIANT INTENSITY VS. AMBIENT TEMPERATURE

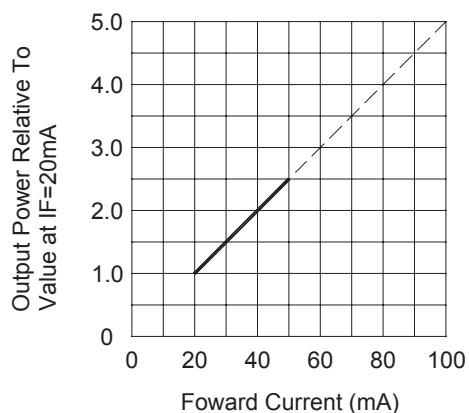


Figure 5. RELATIVE RADIANT INTENSITY VS. FORWARD CURRENT

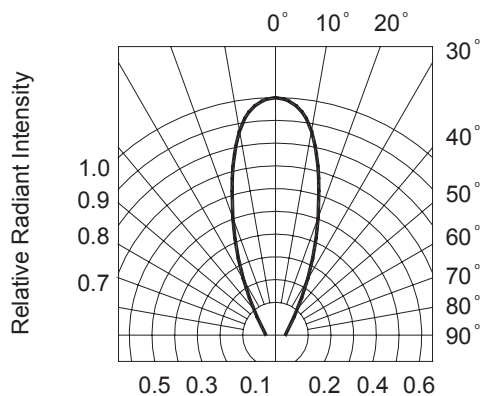


Figure 6. RADIATION DIAGRAM

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